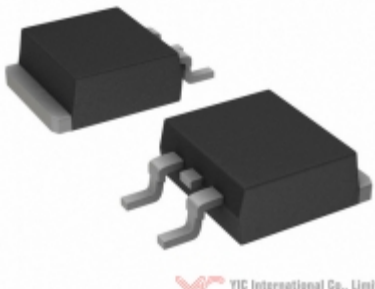








	<h2 style="color: #E67E22;">FQB10N20LTM</h2>
 <p>Image may be representation. See specs for product details.</p>	<b>Hersteller-Teilenummer:</b> <a href="#">FQB10N20LTM</a>
	<b>Hersteller / Marke:</b> <a href="#">Fairchild/ON Semiconductor</a>
	<b>Teil der Beschreibung:</b> MOSFET N-CH 200V 10A D2PAK
	<b>Datenblätter:</b>  <a href="#">FQB10N20LTM.pdf</a>
	<b>RoHs Status:</b> Bleifrei / RoHS-konform
	<b>Lagerzustand:</b> New original, 35563 pcs Stock Available.
<b>Liefern von:</b> Hong Kong	
<b>Versandweg:</b> DHL/Fedex/TNT/UPS/EMS	

### Spezifikationen

Teilenummer	<a href="#">FQB10N20LTM</a>
Hersteller	<a href="#">Fairchild/ON Semiconductor</a>
Beschreibung	MOSFET N-CH 200V 10A D2PAK
Kategorie	<a href="#">Diskrete Halbleiterprodukte &gt; Transistoren-FETs,</a>
Teilstatus	35563 pcs Stock
Serie	QFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-263-3, D <sup>2</sup> Pak (2 Leads + Tab), TO-263AB
Supplier Device-Gehäuse	D <sup>2</sup> PAK (TO-263AB)
Verlustleistung (max)	3.13W (Ta), 87W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	200V
Strom - Ununterbrochener Abfluss (Id) bei 25 °C	10A (Tc)
Rds On (Max) @ Id, Vgs	360 mOhm @ 5A, 10V
VGS (th) (Max) @ Id	2V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	17nC @ 5V
Eingabekapazität (Ciss) (Max) @ Vds	830pF @ 25V
Verpackung	Tape & Reel (TR)












































FQB10N20LTM ist neu im Original, Suche FQB10N20LTM Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FQB10N20LTM Fairchild/ON Semiconductor mit Garantie und Vertrauen. Anfrage FQB10N20LTM: [Info@Y-IC.com](mailto:Info@Y-IC.com)

Sie können auch interessiert sein:

 <b>FQB10N50CF</b> FAIRCHI FQB10N50CF FAIRCHI	 <b>FQB10N20L</b> FAIRCHILD FQB10N20L FAIRCHILD	 <b>FQB10N20TM</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 200V 10A D2PAK	 <b>FQB10N20TM</b> Fairchild/ON Semiconductor MOSFET N-CH 200V 10A D2PAK
 <b>FQB060AN08AO</b> FAIRCHILD FAIRCHILD TO-263	 <b>FQB10N20CTM</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 200V 9.5A D2PAK	 <b>FQB10N20LTM</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 200V 10A D2PAK	 <b>FQB10N50CFTM</b> FSC FQB10N50CFTM FSC

heiße Teile

Mehr

 FQB10N20C	 FQB10N20CTM	 FQB10N20CTM	D FQB10N20L	 FQB10N20LTM
 FQB10N20TM	 FQB10N20TM	D FQB10N50CF	 FQB10N50CFTM	 FQB10N50CFTM_WS
 FQB10N60C	 FQB10N60CTM	 FQB10N60CTM	 FQB11N40	 FQB11N40C
D FQB11N40CTM	 FQB11N40CTM	 FQB11N60FTM	 FQB11N60TM	 FQB11P06
 FQB11P06TM	 FQB11P06TM	 FQB11P06TM**CN-SCI	 FQB12N50TM	 FQB12N50TM_AM002
 FQB12N50TM_AM002	 FQB12N60	D FQB12N60C	 FQB12N60CTM	 FQB12N60CTM
 FQB12N60TM	D FQB12N60TM_AM002	 FQB12N60TM_AM002	 FQB12P10	 FQB12P10TM
 FQB12P10TM	 FQB12P20	 FQB12P20TM	 FQB12P20TM	 FQB13N06L
 FQB13N10	 FQB13N10L	 FQB13N50	D FQB13N50CTM	 FQB13N50CTM
 FQB140N03L	 FQB14N30TM	 FQB14N30TM	 FQB16N25TM	 FQB16N25TM

Contact us: [Info@Y-IC.com](mailto:Info@Y-IC.com)

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